

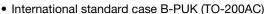
Phase Control Thyristors (Hockey PUK Version), 790 A



B-PUK (TO-200AC)

FEATURES

- · Center amplifying gate
- Metal case with ceramic insulator





 Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

- DC motor control
- Controlled DC power supplies
- AC controllers

PRIMARY CHARACTERISTICS					
I _{T(AV)}	790 A				
V _{DRM} /V _{RRM}	2000 V, 2200 V, 2400 V				
V _{TM}	2.07 V				
I _{GT}	100 mA				
T_J	-40 °C to +125 °C				
Package	B-PUK (TO-200AC)				
Circuit configuration	Single SCR				

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
		790	А		
I _{T(AV)}	T _{hs}	55	°C		
1		1557	А		
I _T (RMS)	T _{hs}	25	°C		
I _{TSM}	50 Hz	10 100	Δ.		
	60 Hz	10 700	A A		
l ² t	50 Hz	510	1.42-		
	60 Hz	475	- kA ² s		
V _{DRM} /V _{RRM}		2000 to 2400	V		
tq	Typical	200	μs		
TJ		-40 to +125	°C		

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS							
TYPE NUMBER	VOLTAGE CODE	V _{DRM} /V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	I_{DRM}/I_{RRM} MAXIMUM AT T _J = T _J MAXIMUM mA			
	20	2000	2100				
VS-ST650CL	22	2200	2300	80			
	24	2400	2500				



ABSOLUTE MAXIMUM RATIN	IGS								
PARAMETER	SYMBOL		TEST CONDITIONS			UNITS			
Maximum average on-state current	l=	180° condu	180° conduction, half sine wave			180° conduction, half sine wave		790 (324)	Α
at heatsink temperature	I _{T(AV)}	Double side	(single side) co	ooled	55 (85)	°C			
Maximum RMS on-state current	I _{T(RMS)}	DC at 25 °C	heatsink tempe	erature double side cooled	1857				
		t = 10 ms	No voltage		10 100				
Maximum peak, one-cycle	I	t = 8.3 ms	reapplied		10 700	Α			
non-repetitive surge current	I _{TSM}	t = 10 ms	100 % V _{RRM}		8600				
		t = 8.3 ms	reapplied	Sinusoidal half wave,	9150				
Maximum I ² t for fusing		t = 10 ms	No voltage	initial $T_J = T_J$ maximum	510	kA ² s			
	I ² t	t = 8.3 ms	reapplied		475				
	1-1	t = 10 ms	100 % V _{RRM} reapplied		370				
		t = 8.3 ms			347				
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reapplied			5100	kA²√s			
Low level value of threshold voltage	V _{T(TO)1}	(16.7 % x π	(16.7 % x π x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$), $T_J = T_J$ maximum			V			
High level value of threshold voltage	V _{T(TO)2}	$(I > \pi \times I_{T(AV)})$), $T_J = T_J$ maxin	num	1.13	V			
Low level value of on-state slope resistance	r _{t1}	(16.7 % x π	(16.7 % x π x I _{T(AV)} < I < π x I _{T(AV)}), T _J = T _J maximum			mΩ			
High level value of on-state slope resistance	r _{t2}	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$ 0.3				1115.2			
Maximum on-state voltage	V _{TM}	$I_{pk} = 1700 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sine pulse}$			2.07	V			
Maximum holding current	I _H	T _ 05 °C	· ·			mΛ			
Typical latching current	ΙL	1) = 25 °C,	T _J = 25 °C, anode supply 12 V resistive load			mA			

SWITCHING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 Ω , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%$ V _{DRM}	1000	A/µs	
Typical delay time	t _d	Gate current 1 A, $dI_g/dt = 1 A/\mu s$ $V_d = 0.67 \% V_{DRM}$, $T_J = 25 °C$	1.0	110	
Maximum turn-off time	tq	I_{TM} = 750 A, T_J = T_J maximum, dI/dt = 60 A/ μ s V_B = 50, dV/dt = 20 V/ μ s, Gate 0 V 100 Ω , t_D = 500 μ s	200	μs	

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum linear to 80 % rated V_{DRM}	500	V/µs
Maximum peak reverse and off-state leakage current	I _{RRM} , I _{DRM}	$T_J = T_J$ maximum, rated V_{DRM}/V_{RRM} applied	80	mA



TRIGGERING							
DADAMETED		TE	TEGT COMPLTIONS		VALUES		
PARAMETER	SYMBOL	15	ST CONDITIONS	TYP.	MAX.	UNITS	
Maximum peak gate power	P _{GM}	$T_J = T_J$ maximum,	$t_p \le 5 \text{ ms}$	10	0.0	W	
Maximum average gate power	P _{G(AV)}	$T_J = T_J$ maximum,	f = 50 Hz, d% = 50	2	.0	VV	
Maximum peak positive gate current	I _{GM}			3	.0	Α	
Maximum peak positive gate voltage	+ V _{GM}	$T_J = T_J$ maximum, $t_p \le 5$ ms		.0	V		
Maximum peak negative gate voltage	- V _{GM}				.0	7	
	I _{GT}	T _J = -40 °C	Maximum required gate trigger/ current/voltage are the lowest	200	-		
DC gate current required to trigger		T _J = 25 °C		100	200	mA	
		T _J = 125 °C		50	-		
		T _J = -40 °C	value which will trigger all units	2.5	-		
DC gate voltage required to trigger	V_{GT}	T _J = 25 °C	12 V anode to cathode applied	1.8	3.0	V	
	T _J = 125 °C			1.1	-		
DC gate current not to trigger	I _{GD}		Maximum gate current/voltage	1	0	mA	
DC gate voltage not to trigger	V _{GD}	$T_J = T_J \text{ maximum}$	not to trigger is the maximum value which will not trigger any unit with rated V _{DRM} anode to cathode applied	0.	25	V	

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum operating temperature range	TJ		-40 to 125	°C		
Maximum storage temperature range	T _{Stg}		-40 to 150			
Maximum thermal resistance in action to be stainly	R _{thJ-hs}	DC operation single side cooled	0.073			
Maximum thermal resistance, junction to heatsink		DC operation double side cooled	0.031	K/W		
Maximum thermal resistance, case to heatsink	R _{thC-hs}	DC operation single side cooled	0.011	N/ VV		
Maximum thermal resistance, case to heatsink		DC operation double side cooled	0.006	1		
Mounting force, ± 10 %			14 700 (1500)	N (kg)		
Approximate weight			255	g		
Case style		See dimensions - link at the end of datasheet	B-PUK (TO-	-200AC)		

△R _{thJ-hs} CONDUCTION							
CONDUCTION ANGLE	SINUSOIDAL	SINUSOIDAL CONDUCTION		RCONDUCTION	TEST CONDITIONS	UNITS	
CONDUCTION ANGLE	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE	TEST CONDITIONS	UNITS	
180°	0.009	0.009	0.006	0.006	$T_J = T_J$ maximum		
120°	0.011	0.011	0.011	0.011			
90°	0.014	0.014	0.015	0.015		K/W	
60°	0.020	0.020	0.021	0.021			
30°	0.036	0.036	0.036	0.036			

Note

• The table above shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC

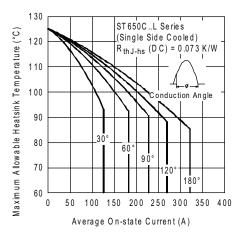


Fig. 1 - Current Ratings Characteristics

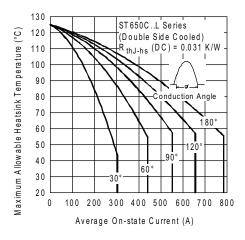


Fig. 2 - Current Ratings Characteristics

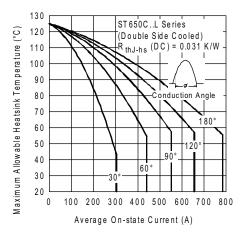


Fig. 3 - Current Ratings Characteristics

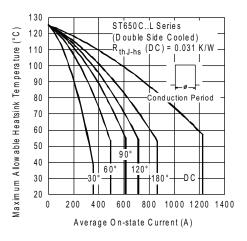


Fig. 4 - Current Ratings Characteristics

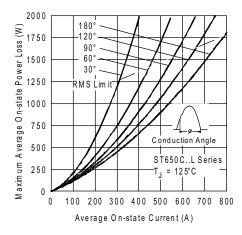


Fig. 5 - On-State Power Loss Characteristics

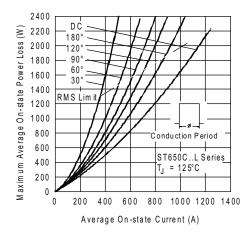


Fig. 6 - On-State Power Loss Characteristics

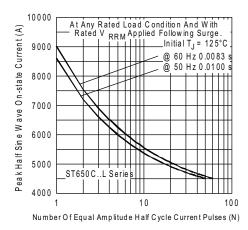


Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

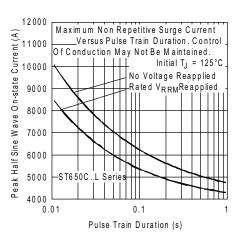


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

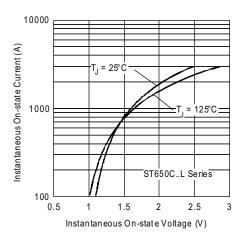


Fig. 9 - On-State Voltage Drop Characteristics

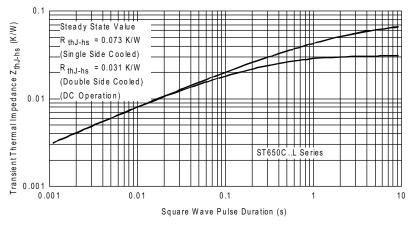


Fig. 10 - Thermal Impedance Z_{thJ-hs} Characteristics

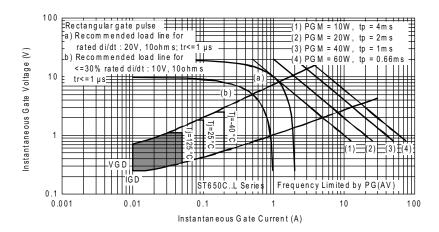
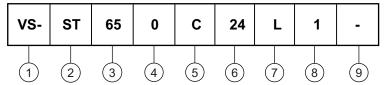


Fig. 11 - Gate Characteristics

ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- 2 Thyristor
- 3 Essential part number
- 0 = converter grade
- 5 C = ceramic PUK
- 6 Voltage code x 100 = V_{RRM} (see Voltage Ratings table)
- 7 L = PUK case B-PUK (TO-200AC)
- 8 0 = eyelet terminals (gate and auxiliary cathode unsoldered leads)
 - 1 = fast-on terminals (gate and auxiliary cathode unsoldered leads)
 - 2 = eyelet terminals (gate and auxiliary cathode soldered leads)
 - 3 = fast-on terminals (gate and auxiliary cathode soldered leads)
- 9 Critical dV/dt: none = 500 V/μs (standard selection)
 L = 1000 V/μs (special selection)

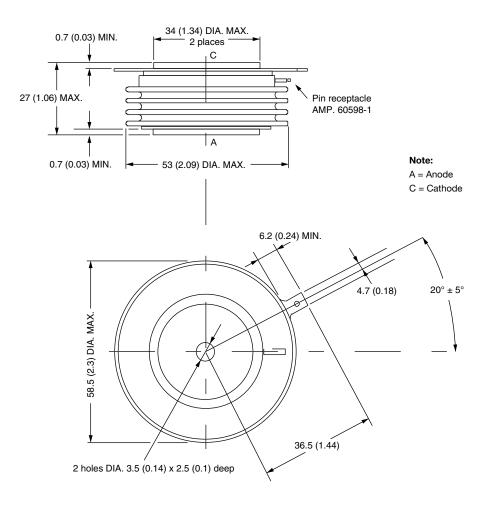
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95076			



B-PUK (TO-200AC)

DIMENSIONS in millimeters (inches)

Creepage distance: 36.33 (1.430) minimum Strike distance: 17.43 (0.686) minimum



Quote between upper and lower pole pieces has to be considered after application of mounting force (see thermal and mechanical specification)



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